MOS FIELD EFFECT TRANSISTOR μ PA2451

PACKAGE DRAWING (Unit : mm)

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

NEC

The μ PA2451 is a switching device which can be driven directly by a 2.5 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 2.5 V drive available
- Low on-state resistance $R_{DS(on)1} = 20 \text{ m}\Omega \text{ MAX.}$ (VGs = 4.5 V, ID = 4.0 A) $R_{DS(on)2} = 21 \text{ m}\Omega \text{ MAX.}$ (VGs = 4.0 V, ID = 4.0 A) $R_{DS(on)3} = 25 \text{ m}\Omega \text{ MAX.}$ (VGs = 3.1 V, ID = 4.0 A) $R_{DS(on)4} = 32 \text{ m}\Omega \text{ MAX.}$ (VGs = 2.5 V, ID = 4.0 A)
- Built-in G-S protection diode against ESD

ORDERING INFORMATION

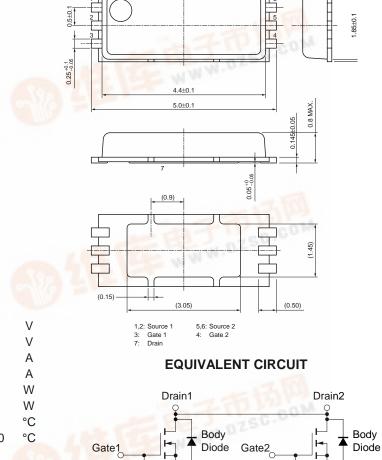
PART NUMBER	PACKAGE
μPA2451TL	6PIN HWSON (4521)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	30
Gate to Source Voltage (VDS = 0 V)	Vgss	±12
Drain Current (DC) ($T_A = 25^{\circ}C$)	ID(DC)	±8.2
Drain Current (pulse) Note1	D(pulse)	±80
Total Power Dissipation (2unit) Note2	PT1	2.5
Total Power Dissipation (2unit) Note3	Рт2	0.7
Channel Temperature	Tch	150
Storage Temperature	Tstg	–55 to +150

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. T_A = 25°C Mounted on ceramic board
- **3.** T_A = 25°C Mounted on FR4 board



Gate

Diode

Protection

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Source2

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Gate

Diode

Protection

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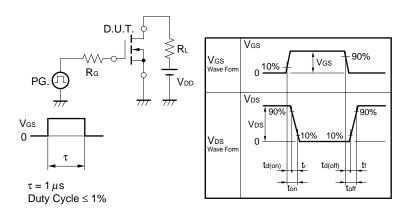
Source1



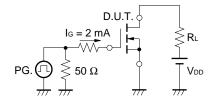
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 30 V, V_{GS} = 0 V$			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 12 V$, $V_{DS} = 0 V$			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = 10 V, I_{D} = 1.0 mA$	0.5	1.0	1.5	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = 10 V, I_D = 4.0 A$	5.0			S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 4.5 V, I_{D} = 4.0 A$	12	16	20	mΩ
	RDS(on)2	$V_{GS} = 4.0 V, I_{D} = 4.0 A$	12.5	16.5	21	mΩ
	RDS(on)3	$V_{GS} = 3.1 \text{ V}, \text{ Id} = 4.0 \text{ A}$	14	18.5	25	mΩ
	RDS(on)4	Vgs = 2.5 V, ID = 4.0 A	15.5	22.5	32	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		540		pF
Output Capacitance	Coss	V _G s = 0 V		150		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		80		pF
Turn-on Delay Time	td(on)	$V_{DD} = 15 V, I_D = 4.0 A$		17		ns
Rise Time	tr	Vgs = 10 V		45		ns
Turn-off Delay Time	td(off)	R _G = 6.0 Ω		360		ns
Fall Time	tf			160		ns
Total Gate Charge	QG	V _{DD} = 24 V		9.0		nC
Gate to Source Charge	QGS	Vgs = 4.0 V		1.5		nC
Gate to Drain Charge	Qgd	ID = 8.2 A		4.5		nC
Body Diode Forward Voltage	VF(S-D)	IF = 8.2 A, VGS = 0 V		0.84		V
Reverse Recovery Time	trr	IF = 8.2 A, VGS = 0 V		160		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A / <i>µ</i> s		200		nC

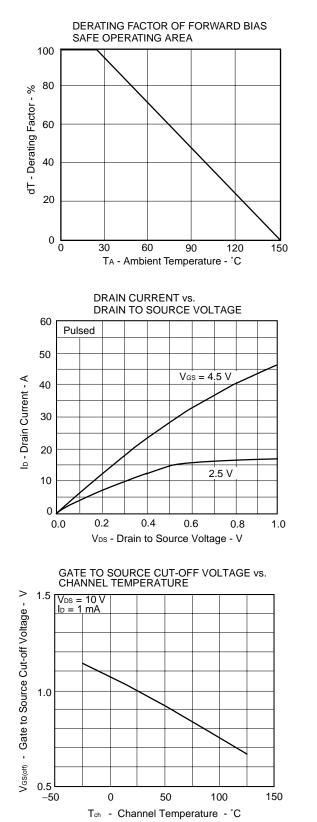
TEST CIRCUIT 1 SWITCHING TIME

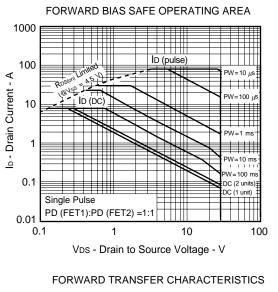


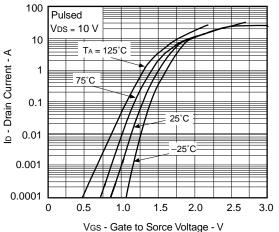
TEST CIRCUIT 2 GATE CHARGE



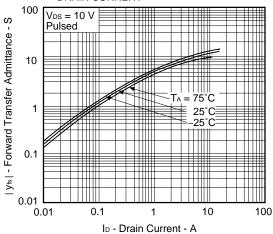




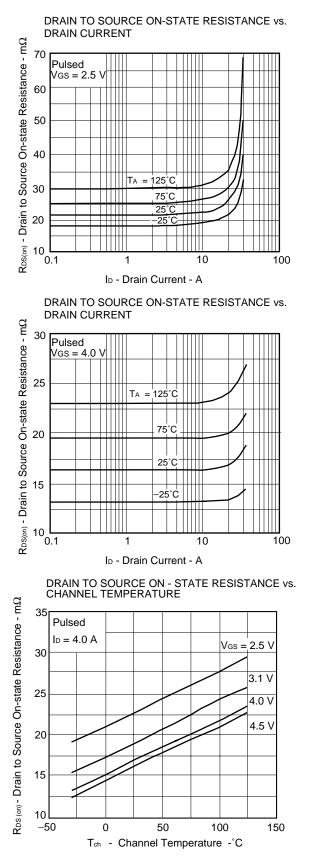


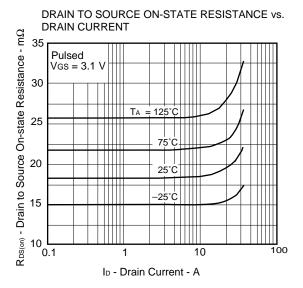


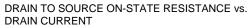
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

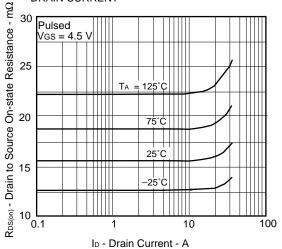


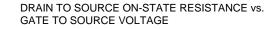
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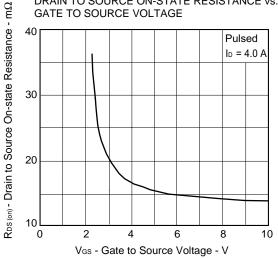




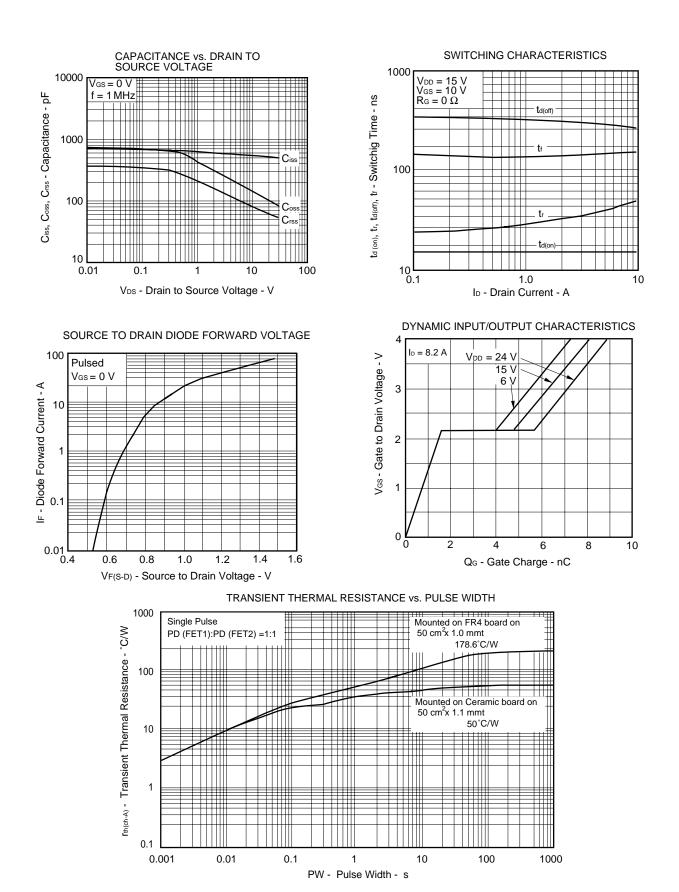








Data Sheet G15621EJ1V0DS



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